MT2

Sensitive Gate TRIACSSilicon Bidirectional Thyristors

Designed for high volume, low cost, industrial and consumer applications such as motor control; process control; temperature, light and speed control.

- Small Size Surface Mount DPAK Package
- · Passivated Die for Reliability and Uniformity
- Four-Quadrant Triggering
- Blocking Voltage to 600 V
- On-State Current Rating of 4.0 Amperes RMS at 93°C
- Low Level Triggering and Holding Characteristics

ORDERING INFORMATION

- To Obtain "DPAK" in Surface Mount Leadform (Case 369A)
 Shipped in Sleeves No Suffix, i.e. MAC4DHM
 Shipped in 16 mm Tape and Reel Add "T4" Suffix to Device Number, i.e. MAC4DHMT4
- To Obtain "DPAK" in Straight Lead Version (Case 369) Shipped in Sleeves Add "-1" Suffix to Device Number, i.e. MAC4DHM-1

MAC4DHM MAC4DLM

Motorola Preferred Devices

TRIACS 4.0 AMPERES RMS 600 VOLTS



MAXIMUM RATINGS (T. I = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
, , , , , , , , , , , , , , , , , , , ,	C4DHM C4DLM	600 600	Volts
On–State RMS Current (Full Cycle Sine Wave, 60 Hz, T _C = 93°C)	I _{T(RMS)}	4.0	Amps
Peak Non–Repetitive Surge Current (One Full Cycle, 60 Hz, T _J = 110°C)	ITSM	40	
Circuit Fusing Consideration (t = 8.3 msec)	I ² t	6.6	A ² sec
Peak Gate Power (Pulse Width ≤ 10 μsec, T _C = 93°C)	PGM	0.5	Watts
Average Gate Power (t = 8.3 msec, T _C = 93°C)	PG(AV)	0.1	
Peak Gate Current (Pulse Width ≤ 10 μsec, T _C = 93°C)	I _{GM}	0.2	Amps
Peak Gate Voltage (Pulse Width ≤ 10 μsec, T _C = 93°C)	V _{GM}	5.0	Volts
Operating Junction Temperature Range	TJ	-40 to 110	°C
Storage Temperature Range	T _{stg}	-40 to 150	

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance — Junction to Case — Junction to Ambient — Junction to Ambient (2)	R _θ JC R _θ JA R _θ JA	R _θ JC 3.5 R _θ JA 88 R _θ JA 80	
Maximum Lead Temperature for Soldering Purposes (3)	TL	260	°C

- (1) VDRM for all types can be applied on a continuous basis. Ratings apply for zero or negative gate voltage; positive gate voltage shall not be applied concurrent with negative potential on the anode. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the device are exceeded.
- (2) Surface mounted on minimum recommended pad size.
- (3) 1/8" from case for 10 seconds.

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referred devices are Motorola recommended choices for future use and best overall value.



ELECTRICAL CHARACTERISTICS ($T_J = 25^{\circ}C$ unless otherwise noted)

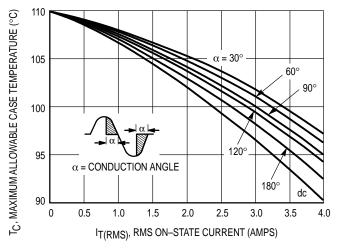
Characteristics	Symbol	Min	Тур	Max	Unit
Peak Repetitive Blocking Current $(V_D = Rated \ V_{DRM}, \ Gate \ Open)$ $T_J = 25^{\circ}C$ $T_J = 110^{\circ}C$	IDRM	_	_	0.01 2.0	mA
Peak On-State Voltage (1) (I _{TM} = ±6.0 A)	Vтм		1.3	1.6	Volts
Gate Trigger Current (Continuous dc) (V_D = 12 V, R_L = 100 Ω) MT2(+), G(+) MAC4DLM MT2(+), G(-) MT2(-), G(-) MT2(-), G(+) MT2(+), G(-) MT2(+), G(-) MT2(-), G(-) MT2(-), G(-)	^I GT		1.8 2.1 2.4 4.2 1.8 2.1 2.4 4.2	3.0 3.0 3.0 5.0 5.0 5.0 5.0	mA
Gate Trigger Voltage (Continuous dc) (V _D = 12 V, R _L = 100 Ω) MT2(+), G(+) (G(-) (MT2(-), G(-) (MT2(-), G(-) (V) = 12 V, R _L = 10 K Ω , T _J = 110°C) MT2(+), G(+); MT2(+), G(-); MT2(-), G(-); MT2(-), G(+)	VGТ	0.5 0.5 0.5 0.5	0.62 0.57 0.65 0.74	1.3 1.3 1.3 1.3	Volts
Holding Current ($V_D = 12 \text{ V}$, Gate Open, $I_T = \pm 200 \text{ mA}$)	lн	_	1.5	15	mA
$\begin{array}{lll} \text{Latching Current} \\ \text{MT2(+), G(+)} & (\text{V}_D = 12 \text{ V}, \text{I}_G = 5.0 \text{ mA}) \\ \text{MT2(+), G(-)} & (\text{V}_D = 12 \text{ V}, \text{I}_G = 5.0 \text{ mA}) \\ \text{MT2(-), G(-)} & (\text{V}_D = 12 \text{ V}, \text{I}_G = 5.0 \text{ mA}) \\ \text{MT2(-), G(+)} & (\text{V}_D = 12 \text{ V}, \text{I}_G = 10 \text{ mA}) \end{array}$	lι	_ _ _ _	1.75 5.2 2.1 2.2	10 10 10 10	mA

DYNAMIC CHARACTERISTICS

Characteristics	Symbol	Min	Тур	Max	Unit
Rate of Change of Commutating Current (1) $(V_D=200~V,~I_{TM}=1.8~A,~Commutating~dv/dt=1.0~V/\mu sec,~T_J=110^{\circ}C,~f=250~Hz,~CL=5.0~\mu fd,~LL=80~mH,~RS=56~\Omega,~CS=0.03~\mu fd)$ See Figure 10	di/dt(c)		3.0		A/ms
Critical Rate of Rise of Off–State Voltage (V _D = 0.67 X Rated V _{DRM} , Exponential Waveform, Gate Open, T _J = 110°C)	dv/dt	ı	10		V/μs

⁽¹⁾ Pulse test: Pulse Width ≤ 2.0 msec, Duty Cycle ≤ 2%.

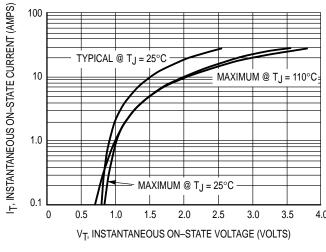
Maria Transport



6.0 P(AV), AVERAGE POWER DISSIPATION (WATTS) dc 180° 5.0 120° 90 4.0 α = CONDUCTION ANGLE 3.0 2.0 60° 1.0 0 0 0.5 1.0 1.5 2.0 2.5 3.0 3.5 4.0 I_{T(RMS)}, RMS ON-STATE CURRENT (AMPS)

Figure 1. RMS Current Derating

Figure 2. On-State Power Dissipation



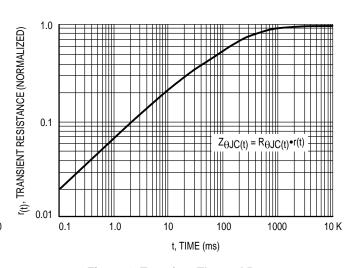
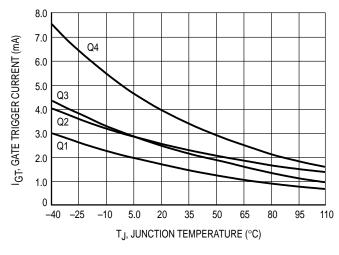


Figure 3. On-State Characteristics

Figure 4. Transient Thermal Response



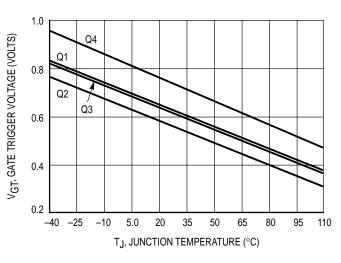


Figure 5. Typical Gate Trigger Current versus Junction Temperature

Figure 6. Typical Gate Trigger Voltage versus
Junction Temperature

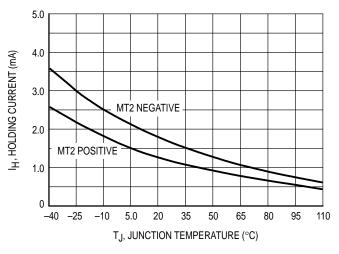


Figure 7. Typical Holding Current versus Junction Temperature

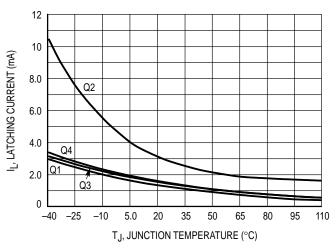


Figure 8. Typical Latching Current versus Junction Temperature

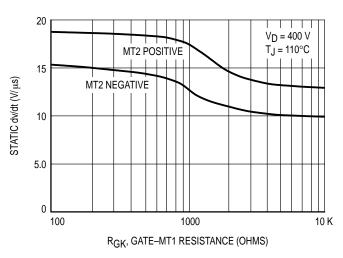


Figure 9. Exponential Static dv/dt versus Gate–MT1 Resistance, MT2(+)

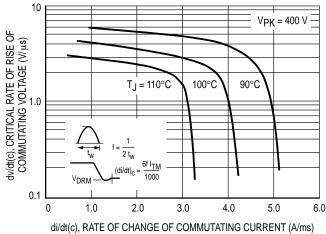


Figure 10. Critical Rate of Rise of Commutating Voltage

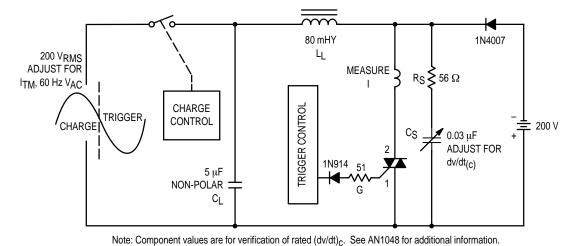
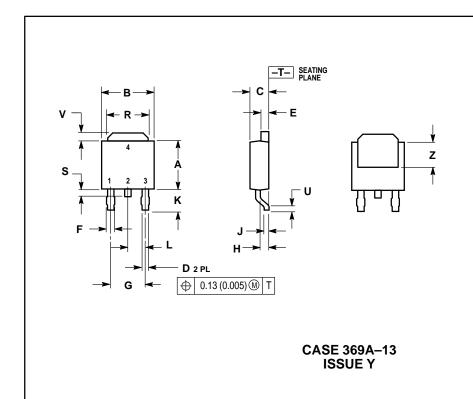


Figure 11. Simplified Test Circuit to Measure the Critical Rate of Rise of Commutating Voltage

PACKAGE DIMENSIONS



NOTES

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: INCH.

	INC	HES	MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.235	0.250	5.97	6.35	
В	0.250	0.265	6.35	6.73	
С	0.086	0.094	2.19	2.38	
D	0.027	0.035	0.69	0.88	
Е	0.033	0.040	0.84	1.01	
F	0.037	0.047	0.94	1.19	
G	0.180 BSC		4.58	BSC	
Н	0.034	0.040	0.87	1.01	
J	0.018	0.023	0.46	0.58	
K	0.102	0.114	2.60	2.89	
L	0.090 BSC		2.29 BSC		
R	0.175	0.215	4.45	5.46	
S	0.020	0.050	0.51	1.27	
U	0.020		0.51		
٧	0.030	0.050	0.77	1.27	
Z	0.138		3.51		

STYLE 6: PIN 1. MT1 2. MT2

3. GATE 4. MT2

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